

V <sub>RSM</sub> V <sub>RRM</sub>	V <sub>VRMS</sub>	I <sub>D</sub> (T <sub>amb</sub> = 45 °C) 2,5 A		
V	V	Types	C <sub>max</sub> μF	$R_{min} \Omega$
200 400 800 1200	60 125 250 500	SKB 2/02 L5A SKB 2/04 L5A SKB 2/08 L5A SKB 2/12 L5A	3 000 2 200 1 000 500	1 1,5 3 6

Symbol	Conditions	SKB 2
ID	T <sub>amb</sub> = 45 °C; isolated <sup>1)</sup> chassis <sup>2)</sup>	1,7 A 2,5 A
I <sub>DCL</sub>	T <sub>amb</sub> = 45 °C; isolated <sup>1)</sup> chassis <sup>2)</sup>	1,4 A 2 A
I <sub>FSM</sub>	$T_{vj} = 25 ^{\circ}\text{C}, 10 \text{ms}$ $T_{vj} = 150 ^{\circ}\text{C}, 10 \text{ms}$	58 A 50 A
i <sup>2</sup> t	$T_{vj} = 25 ^{\circ}\text{C},  8,310 \text{ms}$ $T_{vj} = 150 ^{\circ}\text{C},  8,310 \text{ms}$	17 A <sup>2</sup> s 12,5 A <sup>2</sup> s
VF	T <sub>vj</sub> = 25 °C; I <sub>F</sub> = 10 A	1,65 V
V <sub>(TO)</sub>	T <sub>vj</sub> = 150 °C	0,85 A
r <sub>T</sub>	T <sub>vj</sub> = 150 °C	100 m $\Omega$
I <sub>RD</sub>	$\begin{split} T_{vj} &= 25  ^{\circ}\text{C}; \\ V_{RD} &= V_{RRM} \leq 200   \text{V} \\ &\geq 400   \text{V} \\ T_{vj} &= 150  ^{\circ}\text{C}; \end{split}$	20 μΑ 5 μΑ
	V <sub>RD</sub> = V <sub>RRM</sub> ≤ 200 V ≥ 400 V	1 mA 0,6 mA
t <sub>rr</sub>	T <sub>vj</sub> = 25 °C	typ. 10 μs
$f_{G}$		2000 Hz
R <sub>thja</sub>	isolated <sup>1)</sup> chassis <sup>2)</sup>	30 °C/W 17,5 °C/W
$T_{vj}$		– 40+ 150 °C
T <sub>stg</sub>		– 55+ 150 °C
RC	P <sub>R</sub> = 1 W	10 nF+2050 Ω
Fu		2 A
w		4 g
Case	→ page B 11 – 6	G 4

## **Miniature Bridge Rectifiers**

## SKB 2





## **Features**

- · Compact plastic package with in-line terminals
- · High blocking voltage

## **Typical Applications**

- Internal power supplies for electronic equipment
- DC power supplies
- Control equipment
- TV sets

© by SEMIKRON B 11 – 7

<sup>1)</sup> Freely suspended or mounted on an insulator 2) Mounted on a painted metal sheet of min. 250 x 250 x 1 mm

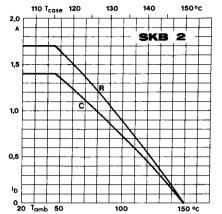


Fig. 1 Rated output current vs. ambient temperature

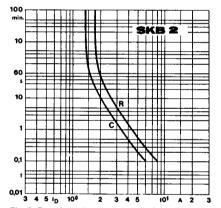


Fig. 6 Rated overload current vs. time

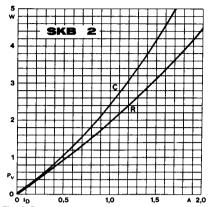


Fig. 2 Power dissipation vs. output current

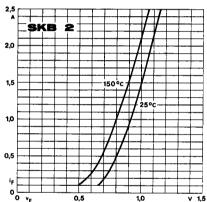
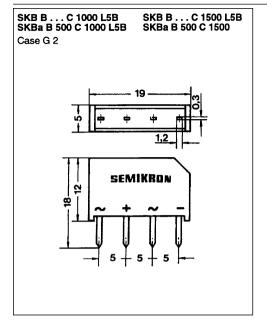
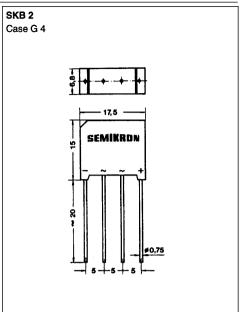


Fig. 9 Forward characteristics of a single diode

B 11 – 8 © by SEMIKRON





Dimensions in mm

B 11 – 6 © by SEMIKRON